Power Amplifier, 4 W 28.5 - 31.0 GHz

Features

- High Gain: 25 dB @ 30 GHz .
- P1dB: 34.5 dBm
- P3dB: 36.0 dBm
- IM3 Level: -27 dBc @ Pout 29 dBm/tone .
- Power Added Efficiency: 27.5% @ P3dB
- Lead-Free 5 mm 32-lead AQFN Package
- **RoHS*** Compliant

Description

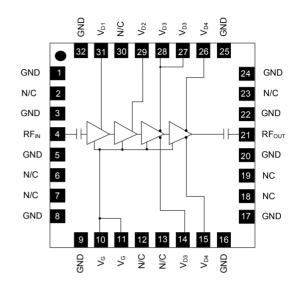
The MAAP-011233 is a 4-stage, 4 W power amplifier assembled in a lead-free 5 mm 32-lead AQFN plastic package. This power amplifier operates from 28.5 to 31.0 GHz and provides 26 dB of linear gain, 4 W saturated output power and 27.5% efficiency while biased at 6 V.

The MAAP-011233 can be used as a power amplifier ideally suited for VSAT communications.

This product is fabricated using a GaAs pHEMT process which features full passivation for enhanced reliability.

1. Reference Application Note M513 for reel size information.

Functional Schematic



Pin Configuration^{3,4}

Pin Name	Description
GND	Ground
N/C	No Connection
RFIN	RF Input
Vg	Gate Voltage
V _{D3}	Drain Voltage 3
V _{D4}	Drain Voltage 4
RFout	RF Output
Vd2	Drain Voltage 2
Vd1	Drain Voltage 1
	GND N/C RFIN VG VD3 VD4 RFOUT VD2

3. MACOM recommends connecting all No Connection (N/C) pins to ground.

The exposed pad centered on the package bottom must be 4 connected to RF, DC and thermal ground.

* Restrictions on Hazardous Substances, compliant to current RoHS EU directive.

Package

Bulk

500 Piece Reel

Sample Board

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Ordering Information^{1,2}

Part Number

MAAP-011233

MAAP-011233-TR0500

MAAP-011233-SMB

2. All sample boards include 3 loose parts.



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Power Amplifier, 4 W 28.5 - 31.0 GHz

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Electrical Specifications: Freq. = 30 GHz, T_A = +25°C, V_D = 6 V, Z_0 = 50 Ω

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Gain	P _{IN} = 0 dBm	dB	22	25.0	_
P _{OUT}	P _{IN} = +14 dBm	dBm	34.5	36.0	_
IM3 Level	P _{OUT} = 29 dBm / tone	dBc		-27.0	
Power Added Efficiency	P _{IN} = +14 dBm	%		27.5	
Input Return Loss	P _{IN} = -20 dBm	dB		10	
Output Return Loss	P _{IN} = -20 dBm	dB		10	
Quiescent Current	I_{DQ} (see bias conditions, page 4)	mA		2000	
Current	P _{IN} = +14 dBm	mA		2800	3600

Maximum Operating Ratings

Parameter	Rating
Input Power	14 dBm
Junction Temperature ^{5,6}	+160°C
Operating Temperature	-40°C to +85°C

5. Operating at nominal conditions with junction temperature \leq +160°C will ensure MTTF > 1 x 10⁶ hours.

6. Junction Temperature $(T_J) = T_C + \Theta_{JC} * [(V * I) - (P_{OUT} - P_{IN})].$ Typical thermal resistance $(\Theta_{JC}) = 4.4 \text{ °C/W}.$

a) For T_C = +25°C,

 $T_J = +82^{\circ}C @ 6 V, 2.8 A, P_{OUT} = 36 dBm, P_{IN} = 14 dBm$ b) For $T_C = +85^{\circ}C$,

 $T_{\rm J}$ = +137°C @ 6 V, 2.5 A, $P_{\rm OUT}$ = 35 dBm, $P_{\rm IN}$ = 14 dBm

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

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These electronics devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these HBM Class 1A devices.

Absolute Maximum Ratings^{7,8}

Parameter	Absolute Maximum
Input Power	20 dBm
Drain Voltage	6.5 V
Gate Voltage	-3 to 0 V
Junction Temperature ⁹	+175°C
Storage Temperature	-65°C to +125°C

7. Exceeding any one or combination of these limits may cause permanent damage to this device.

 MACOM does not recommend sustained operation near these survivability limits.

9. Junction temperature directly effects device MTTF. Junction temperature should be kept as low as possible to maximize lifetime.

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Power Amplifier, 4 W 28.5 - 31.0 GHz

Sample Board Layout

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Parts List

Part	Value	Case Style
C1 - C7	0.01 µF	0402
C8 - C12	1 µF	0603
C13 - C16	10 µF	0805
R1 - R7	10 Ω	0402

Sample Board Material Specifications

Top Layer: 1/2 oz Copper Cladding, 0.017 mm thickness *Dielectric Layer:* Rogers RO4003C 0.203 mm thickness Bottom Layer: 1/2 oz Copper Cladding, 0.017 mm thickness

Finished overall thickness: 0.238 mm

GND GND GND GND GND GNI 1 C ANSCOM MAAP-011233

TERMINALS ARE CONNECTED TOGETHER ON THE

C14		
	Voz Voz	Vo4

GND

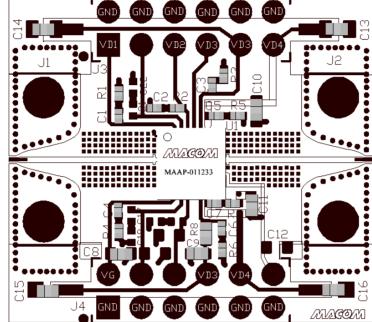
Application Schematic

VD1

 \cap

PCB BY METAL.

VD2 0





Rev. V2

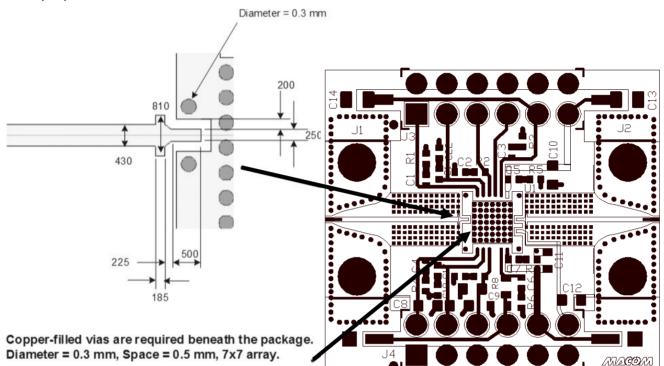
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Power Amplifier, 4 W 28.5 - 31.0 GHz

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Sample Board Layout:

RF input and output port pre-matching circuit patterns are designed to compensate for packaging effects. Input and output patterns are identical.



Biasing Conditions

Recommended biasing conditions are $V_D = 6 V$, $I_{DQ} = 2 A$ (controlled with V_G). The drain bias voltage range is 3 to 6 V, and the quiescent drain current biasing range is 1.5 to 2.5 A.

 V_G pins 10 and 11 are connected internally; choose either pin for layout convenience. Muting can be accomplished by setting the V_G to the pinched off voltage (V_G = -2 V).

 V_{D} bias must be applied to $V_{\text{D}}1,~V_{\text{D}}2,~V_{\text{D}}3,$ and $V_{\text{D}}4$ pins.

 V_D3 pins 14 and either pin 27 or 28 are required for current symmetry. Pins 27 and 28 are connected internally; choose either pin for layout convenience.

Both $V_{\text{D}}4$ pins 15 and 26 are required for current symmetry.

Operating the MAAP-011233

Turn-on

- 1. Apply V_G (-1.5 V).
- 2. Apply $V_{D1},\,V_{D2},\,V_{D3},\,V_{D4}$ (6.0 V typical).
- 3. Set I_{DQ} by adjusting V_G more positive (typically -0.9 to -1.0 V for I_{DQ} = 2 A).
- 4. Apply RF_{IN} signal.

Turn-off

- 1. Remove RF_{IN} signal.
- 2. Decrease V_G to -1.5 V.
- 3. Decrease V_{D1} , V_{D2} , V_{D3} , V_{D4} to 0 V.

Application Information

The MAAP-011233 is designed to be easy to use yet high performance. The ultra small size and simple bias allow easy placement on system board. RF input and output ports are DC de-coupled internally.

For further information and support please visit: https://www.macom.com/support

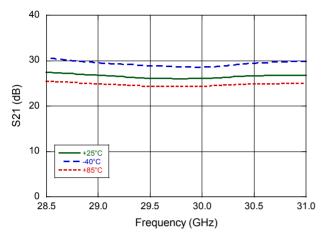
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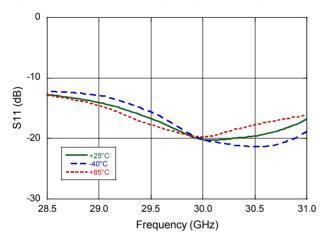
Power Amplifier, 4 W 28.5 - 31.0 GHz

Typical Performance Curves

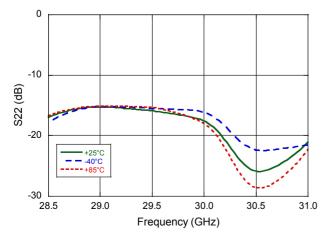
Small Signal Gain vs. Frequency over Temperature



Input Return Loss vs. Frequency over Temperature



Output Return Loss vs. Frequency over Temperature

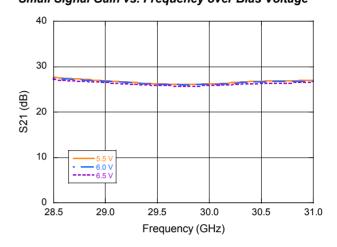


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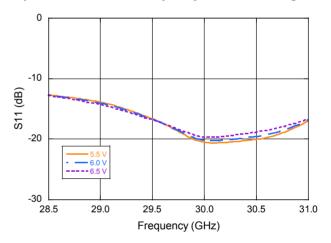


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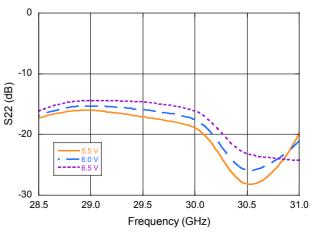
Small Signal Gain vs. Frequency over Bias Voltage



Input Return Loss vs. Frequency over Bias Voltage



Output Return Loss vs. Frequency over Bias Voltage

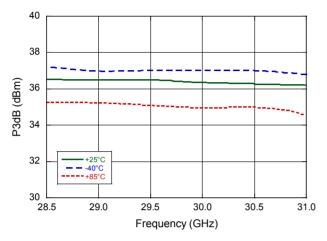


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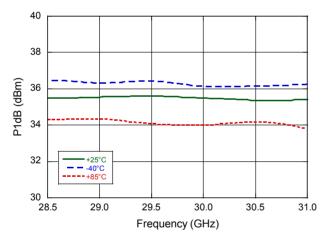
Power Amplifier, 4 W 28.5 - 31.0 GHz

Typical Performance Curves

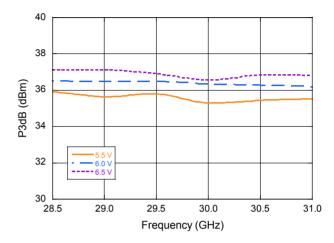
P3dB vs. Frequency over Temperature



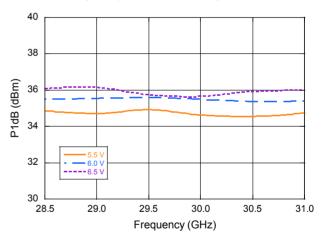
P1dB vs. Frequency over Temperature



P3dB vs. Frequency over Bias Voltage



P1dB vs. Frequency over Bias Voltage



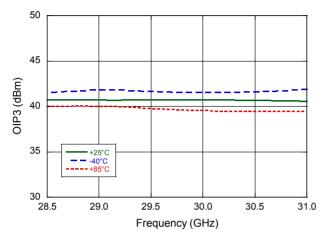
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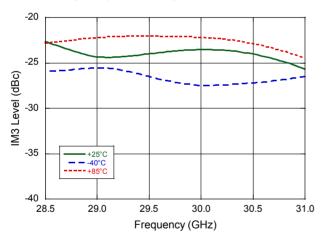
Power Amplifier, 4 W 28.5 - 31.0 GHz

Typical Performance Curves: Pout = 29 dBm / Tone

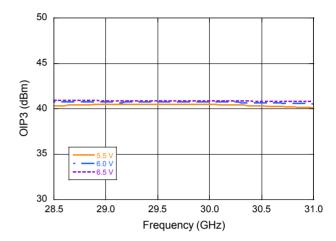
Output IP3 vs. Frequency over Temperature



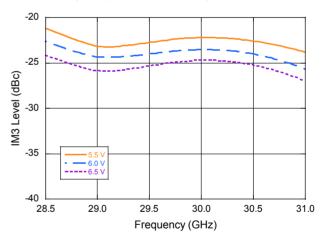
IM3 vs. Frequency over Temperature



Output IP3 vs. Frequency over Bias Voltage



IM3 vs. Frequency over Bias Voltage



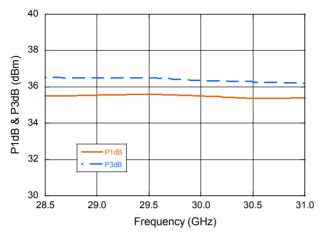
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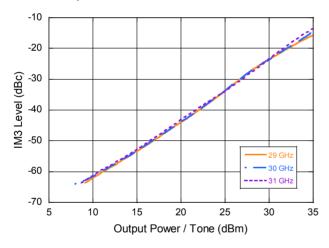
Power Amplifier, 4 W 28.5 - 31.0 GHz



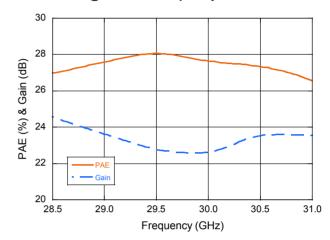
P1dB & P3dB vs. Frequency

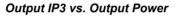


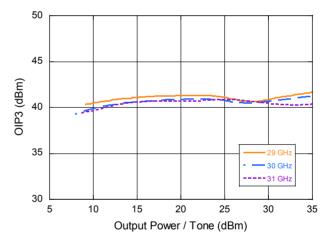
IM3 vs. Output Power



PAE & Gain @ P3dB vs. Frequency







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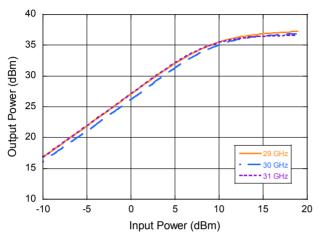
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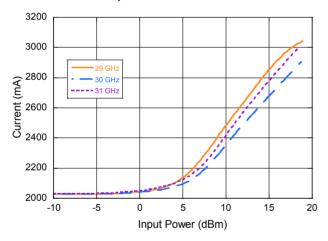
Power Amplifier, 4 W 28.5 - 31.0 GHz

Typical Performance Curves

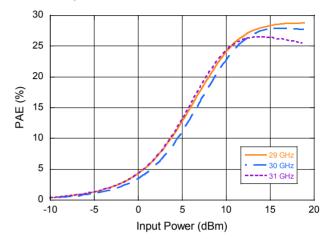
Output Power vs. Input Power



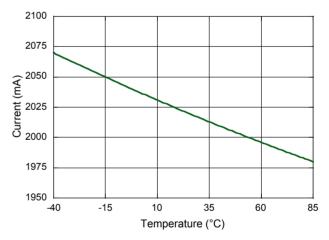
Bias Current vs. Input Power



PAE vs. Input Power



Quiescent Drain Current vs. Temperature



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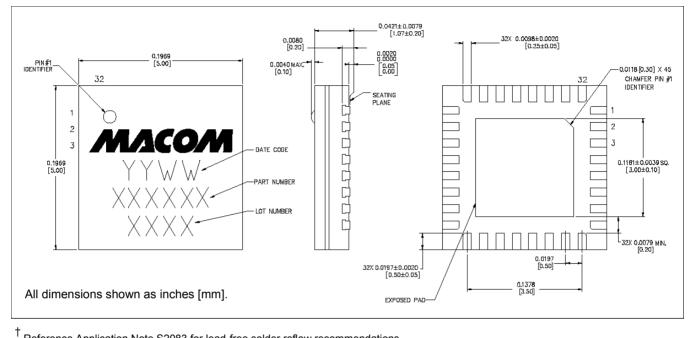




Power Amplifier, 4 W 28.5 - 31.0 GHz

Rev. V2

Lead-Free 5 mm 32-Lead AQFN Package[†]



^T Reference Application Note S2083 for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level 3 requirements. Plating is NiPdAu.

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